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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/043,276	01/14/2002	Goro Nakatani	040894-5755	4701
9629 7.	590 12/14/2005		EXAMINER	
MORGAN LEWIS & BOCKIUS LLP			IM, JUNGHWA M	
WASHINGTO	LVANIA AVENUE NW N. DC 20004		ART UNIT	PAPER NUMBER
	· · · · · ·		2811	
			DATE MAILED: 12/14/2005	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)			
Office Action Commons	10/043,276	NAKATANI ET AL.			
Office Action Summary	Examiner	Art Unit			
	Junghwa M. Im	2811			
The MAILING DATE of this communication appeared for Reply	ears on the cover sheet with the co	orrespondence address			
A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply If NO period for reply is specified above, the maximum statutory period w. - Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	6(a). In no event, however, may a reply be tim within the statutory minimum of thirty (30) days ill apply and will expire SIX (6) MONTHS from to cause the application to become ABANDONED	ely filed will be considered timely. the mailing date of this communication. (35 U.S.C. § 133).			
Status					
1) Responsive to communication(s) filed on 17 No	ovember 2005.				
2a)⊠ This action is FINAL . 2b)☐ This	This action is FINAL . 2b) This action is non-final.				
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is					
closed in accordance with the practice under E	x parte Quayle, 1935 C.D. 11, 45	3 O.G. 213.			
Disposition of Claims					
4) Claim(s) 1,3 and 8-13 is/are pending in the application.					
4a) Of the above claim(s) is/are withdrawn from consideration.					
5) Claim(s) is/are allowed.					
6)⊠ Claim(s) <u>1,3 and 8-13</u> is/are rejected.					
7) Claim(s) is/are objected to.					
8) Claim(s) are subject to restriction and/or	election requirement.				
Application Papers					
9) The specification is objected to by the Examiner	•.				
10) The drawing(s) filed on is/are: a) accepted or b) objected to by the Examiner.					
Applicant may not request that any objection to the o	frawing(s) be held in abeyance. See	37 CFR 1.85(a).			
Replacement drawing sheet(s) including the correction 11) The oath or declaration is objected to by the Example 11.					
Priority under 35 U.S.C. § 119					
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority documents 2. Certified copies of the priority documents 3. Copies of the certified copies of the priori application from the International Bureau * See the attached detailed Office action for a list of	have been received. have been received in Application ity documents have been receive (PCT Rule 17.2(a)).	on No d in this National Stage			
Attachment(s)					
 Notice of References Cited (PTO-892) Notice of Draftsperson's Patent Drawing Review (PTO-948) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date 	4) Interview Summary (Paper No(s)/Mail Dai 5) Notice of Informal Pa 6) Other:	•			

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DETAILED ACTION

The finality of the previous Office action is withdrawn pursuant to the Declaration under 37 CFR 1.131 filed November 17, 2005 to introduce a newly found reference of Braecklemann et al.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

Claims 1, 3, 8 and 10-13 are rejected under 35 U.S.C. 102(e) as being anticipated by Braeckelmann et al. (US 6218302), hereinafter Braeckelmann.

Regarding claim 1, Fig. 11 of Braeckelmann shows semiconductor device comprising: a first interconnect layer (124) arranged above a substrate on which a functional semiconductor region (118) is formed;

an inter layer dielectric (22) covering a surface of the first interconnect layer;

a silicon nitride film (23; col. 3, lines 55-57) formed so as to cover entirely a top surface of said interlayer dielectric,

a metal interconnect layer (83) covering over said silicon nitride film, said metal interconnect layer being consist of gold material (col. 7, lines 23-26); and a planarized polyimide (1102) formed on the metal interconnect layer,

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wherein the polyimide layer is removed at a part of a region of the metal interconnect layer and a bond wire (1104) is connected to the region of the metal interconnect layer.

Regarding claim 3, Braeckelmann discloses that the silicon nitride film is deposited by plasma deposit (col. 3, lines 49-51).

In addition, "high-density plasma CVD" is a process designation, and would thus not carry patentable weight in this claim drawn to a product. See *In re Thorp*, 227 USPQ 964 (Fed. Cir. 1985).

Regarding claim 8, Fig. 11 of Braeckelmann shows a semiconductor device comprising: a first interconnect layer (124) covering a first portion of a surface of a functional semiconductor region (118);

an inter layer dielectric (71) covering a second portion of the surface of the functional semiconductor region and a portion of a surface of said first interconnect layer, thereby forming a contacting hole on the surface of the first interconnect layer;

a silicon nitride film (72; col. 3, lines 55-57) covering a top surface of said inter layer dielectric around the contacting hole on the surface of the first interconnect layer;

a barrier layer (81) covering the contacting hole and a portion of a surface of the silicon nitride film around the contacting hole, thereby forming a barrier layer region (col. 6, lines 62-63);

a metal interconnect region (83) consist of gold material (col. 7, lines 23-26) covering over the barrier region, thereby forming a metal interconnect region; and

a planarized polyimide (1102) covering the metal interconnect layer and the silicon nitride surface around the metal interconnect region

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wherein the polyimide layer is removed at a part of a region of the metal interconnect layer and a bond wire (1104) is connected to the region of the metal interconnect layer.

Regarding claims 10 and 11, Braeckelmann discloses the first interconnect layer consists of aluminum (col. 3, lines 25-26).

Regarding claim 12, Braeckelmann discloses the inter layer dielectric consists of USG film (col. 3, lines 47-49).

Regarding claim 13, Fig. 11 of Braeckelmann shows the functional semiconductor region further comprises a polysilicon gate (108; col.2, lines 57-58) isolated from the first interconnect layer by a second dielectric layer (110), wherein the first interconnect layer is connected to the polysilicon gate through a contacting area (116) disposed within the second dielectric layer.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claim 9 is rejected under 35 U.S.C. 103(a) as being unpatentable over Braeckelmann in view of Toyosawa et al. (US 6441467), hereinafter Toyosawa.

Regarding claim 9, Fig. 11 of Braeckelmann shows substantially the entire claimed structure except "the barrier layer consists of titanium." Toyosawa discloses that the barrier layer consists of titanium (col. 7, lines 48-50).

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It would have been obvious to one of ordinary skill in the art at the time of the invention to incorporate the teaching of Toyosawa to the device of Braeckelmann in order to have the barrier layer consisted of titanium to diffusion of the metallic compound to the neighboring layer while using the well-known barrier material.

Response to Arguments

Applicant's arguments with respect to pending claims have been considered but are moot in view of the new ground(s) of rejection.

Conclusion

Applicant's amendment on October 18, 2004 necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

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Any inquiry concerning this communication or earlier communications from the examiner should be directed to Junghwa M. Im whose telephone number is (571) 272-1655. The examiner can normally be reached on MON.-FRI. 8:30AM-5:00PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Eddie C. Lee can be reached on (571) 272-1732. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

jmi

EDDIE LEE
SUPERVISORY PATENT EXAMINER

TECHNOLOGY CENTER 2800